

## Transistors

# PNP Medium Power Transistor (Switching)

## SST4403 / MMST4403

### ●Features

- 1)  $BV_{CE0} = -40V$  (Min.) ; at  $I_C = -1mA$
- 2) Complements the SST4401 / MMST4401

### ●Package, marking, and packaging specifications

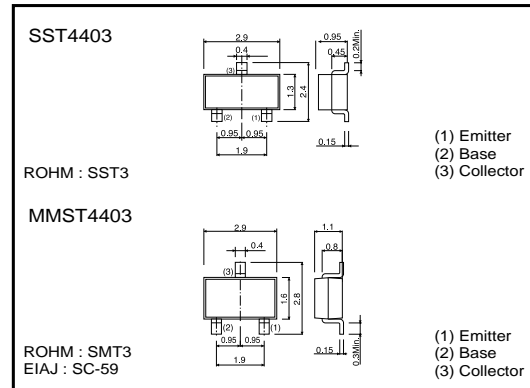
Part No.	SST4403	MMST4403
Packaging type	SST3	SMT3
Marking	R2T	R2T
Code	T116	T146
Basic ordering unit (pieces)	3000	3000

### ●Absolute maximum ratings ( $T_a = 25^\circ C$ )

Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CB0}$	-40	V
Collector-emitter voltage	$V_{CE0}$	-40	V
Emitter-base voltage	$V_{EB0}$	-6	V
Collector current	$I_C$	-0.6	A
Collector power dissipation	$P_C$	0.2	W
		0.35	W
Junction temperature	$T_J$	150	$^\circ C$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ C$

\* Mounted on a 7×5×0.6mm CERAMIC SUBSTRATE

### ●Dimensions (Unit : mm)



### ●Electrical characteristics ( $T_a = 25^\circ C$ )

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CB0}$	-40	-	-	V	$I_C = -100\mu A$
Collector-emitter breakdown voltage	$BV_{CE0}$	-40	-	-	V	$I_C = -1mA$
Emitter-base breakdown voltage	$BV_{EB0}$	-5	-	-	V	$I_E = -100\mu A$
Collector cutoff current	$I_{CBO}$	-	-	-0.1	$\mu A$	$V_{CB} = -35V$
Emitter cutoff current	$I_{EBO}$	-	-	-0.1	$\mu A$	$V_{EB} = -5V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	-	-0.4	V	$I_C/I_E = -150mA/-15mA$
		-	-	-0.75	V	$I_C/I_E = -500mA/-50mA$
Base-emitter saturation voltage	$V_{BE(sat)}$	-0.75	-	-0.95	V	$I_C/I_E = -150mA/-15mA$
		-	-	-1.3	V	$I_C/I_E = -500mA/-50mA$
DC current transfer ratio	$h_{FE}$	30	-	-	-	$V_{CE} = -1V, I_C = -0.1mA$
		60	-	-	-	$V_{CE} = -1V, I_C = -1mA$
		100	-	-	-	$V_{CE} = -1V, I_C = -10mA$
		100	-	300	-	$V_{CE} = -1V, I_C = -150mA$
		20	-	-	-	$V_{CE} = -2V, I_C = -500mA$
Transition frequency	$f_T$	200	-	-	MHz	$V_{CE} = -10V, I_E = 20mA, f = 100MHz$
Collector output capacitance	$C_{ob}$	-	-	8.5	pF	$V_{CB} = -10V, f = 100kHz$
Emitter input capacitance	$C_{ib}$	-	-	30	pF	$V_{EB} = -0.5V, f = 100kHz$
Delay time	$t_d$	-	-	15	ns	$V_{CC} = -30V, V_{EB(OFF)} = -2V, I_C = -150mA, I_{B1} = -15mA$
Rise time	$t_r$	-	-	20	ns	$V_{CC} = -30V, V_{EB(OFF)} = -2V, I_C = -150mA, I_{B1} = -15mA$
Storage time	$t_{stg}$	-	-	225	ns	$V_{CC} = -30V, I_C = -150mA, I_{B1} = -I_{B2} = -15mA$
Fall time	$t_f$	-	-	30	ns	$V_{CC} = -30V, I_C = -150mA, I_{B1} = -I_{B2} = -15mA$

Transistors

●Electrical characteristic curves

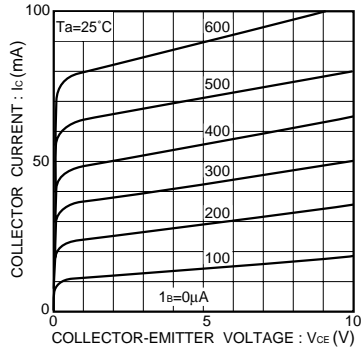


Fig.1 Grounded emitter output characteristics

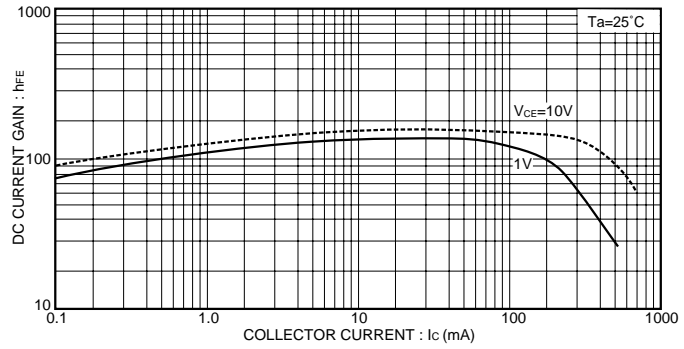


Fig.3 DC current gain vs. collector current (I)

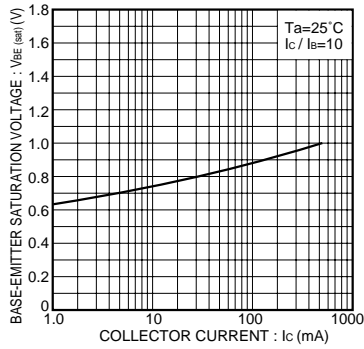


Fig.2 Base-emitter saturation voltage vs. collector current

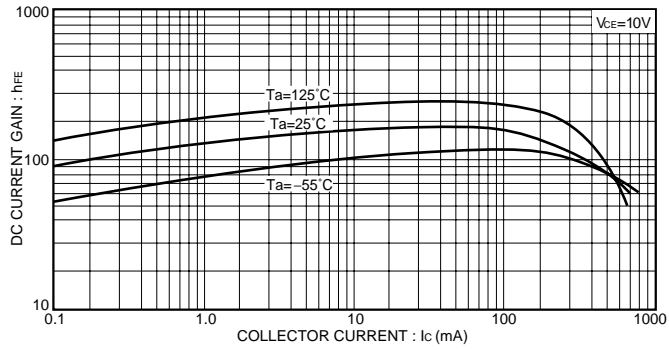


Fig.4 DC current gain vs. collector current (II)

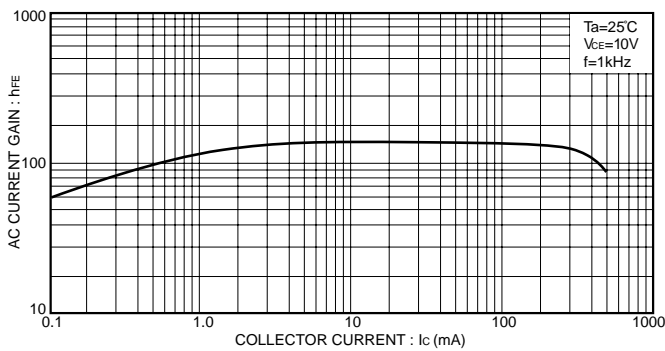


Fig.5 AC current gain vs. collector current

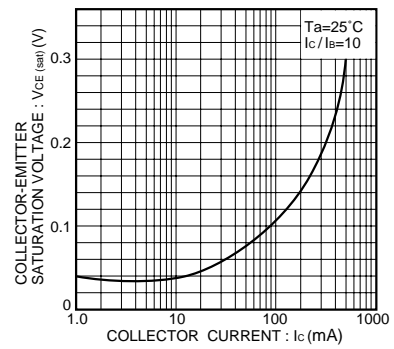


Fig.6 Collector-emitter saturation voltage vs. collector current

Transistors

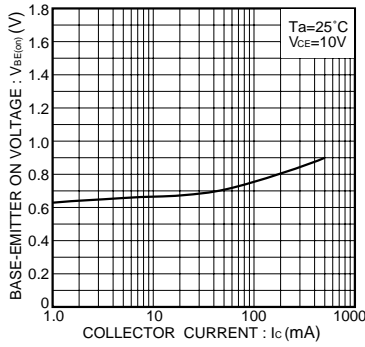


Fig.7 Grounded emitter propagation characteristics

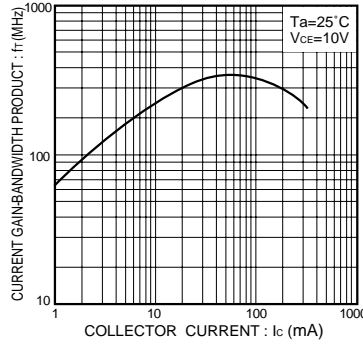


Fig.8 Gain bandwidth product vs. collector current

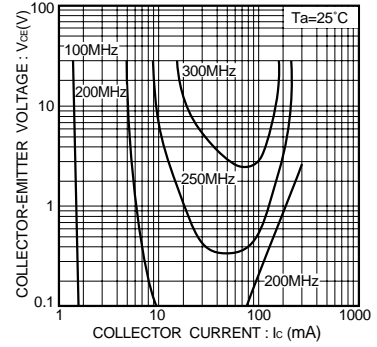


Fig.9 Gain bandwidth product

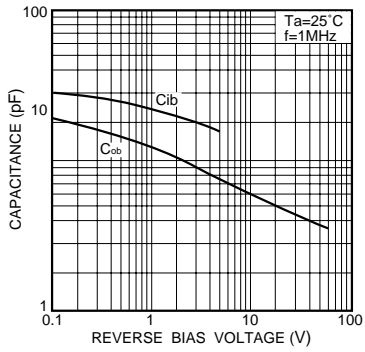


Fig.10 Input/output capacitance vs. voltage

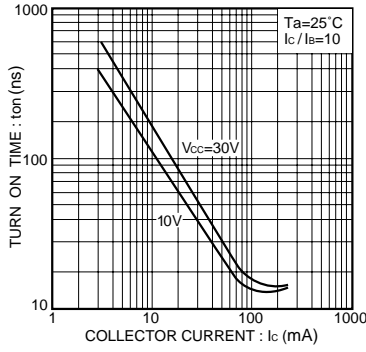


Fig.11 Turn-on time vs. collector current

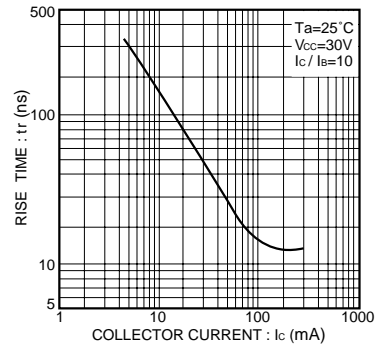


Fig.12 Rise time vs. collector current

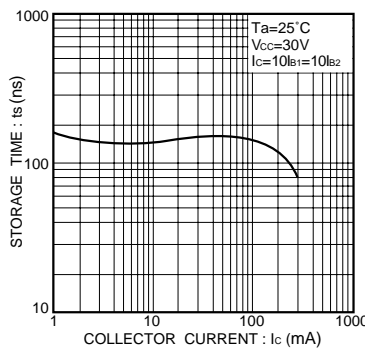


Fig.13 Storage time vs. collector current

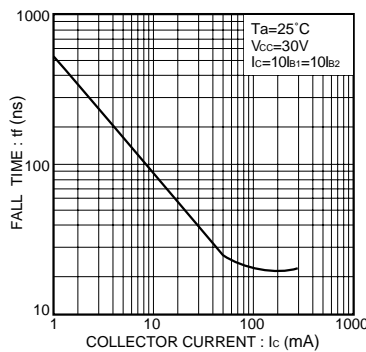


Fig.14 Fall time vs. collector current

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